



# Solid State Devices, Inc.

14701 Firestone Blvd \* La Mirada, Ca 90638  
Phone: (562) 404-4474 \* Fax: (562) 404-1773  
ssdi@ssdi-power.com \* www.ssdi-power.com

## SDR6638, SDR6642, SDR6643, & SDR4150 SERIES

**300 mA**  
**50 - 125 VOLTS**  
**4.5 - 6.0 nsec HYPER FAST RECOVERY**  
**RECTIFIER**

### Designer's Data Sheet

**Part Number/Ordering Information <sup>1/</sup>**

SDR \_\_\_\_\_

- L **Screening <sup>2/</sup>**
  - \_\_\_ = Not Screened
  - TX = TX Level
  - TXV = TXV
  - S = S Level (for SM, use -S)
- L **Package Type**
  - \_\_\_ = Axial Leaded
  - SM = Surface Mount Round Tab (MELF)
  - SMS = Surface Mount Square Tab
- L **Device Type (VRWM)**
  - 6638 = 125 V
  - 6642 = 75 V
  - 6643 = 50 V
  - 4150 = 75 V

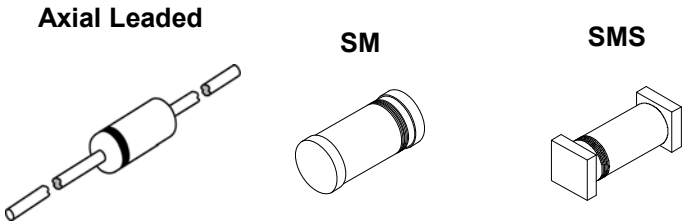
- ### FEATURES:
- Hyper Fast Reverse Recovery Time 4.5 - 6 ns Max
  - Hermetically Sealed
  - Planar Passivated Chip
  - For High Efficiency Applications
  - Available in Axial, Subminiature Round Tab & Subminiature Square Tab Versions
  - TX, TXV, and S-Level Screening Available <sup>2/</sup>
  - Replacement for 1N6638, 1N6642, 1N6643, & 1N4150-1
  - Metallurgical Class 3 Bond

### MAXIMUM RATINGS <sup>3/</sup>

RATING		SYMBOL	VALUE	UNIT
<b>Peak Repetitive Reverse Voltage</b> <b>DC Blocking Voltage</b>	SDR6638	$V_{RWM}$ $V_R$	125	Volts
	SDR6642		75	
	SDR6643		50	
	SDR4150		75	
<b>Average Rectified Forward Current</b> (Resistive Load, 60 Hz, Sine Wave, T <sub>C</sub> = 25°C)		$I_O$	300	mAmps
<b>Peak Surge Current</b> (8.3 msec Pulse, Half Sine Wave Superimposed on I <sub>O</sub> , allow junction to reach equilibrium between pulses, T <sub>C</sub> = 25°C)		$I_{FSM}$	2.5	Amps
<b>Operating &amp; Storage Temperature</b>		T <sub>OP</sub> and T <sub>STG</sub>	-65 to +175	°C
<b>Thermal Resistance</b> SM and SMS- Junction to End Tab Axial- Junction to Lead @ .375"		$R_{\theta JE}$ $R_{\theta JL}$	100 325	°C/W

### NOTES:

- 1/ For Ordering Information, Price, and Availability- Contact Factory.
- 2/ Screening Based on MIL-PRF-19500. Screening Flows Available on Request.
- 3/ Unless Otherwise Specified, All Electrical Characteristics @25°C.





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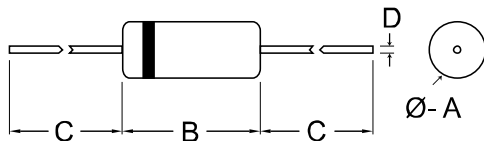
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**SDR6638, SDR6642, SDR6643,  
& SDR4150 SERIES**

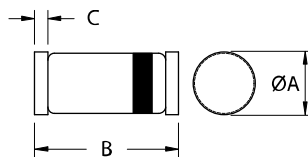
**ELECTRICAL CHARACTERISTICS <sup>3/</sup>**

CHARACTERISTICS		SYMBOL	LIMIT	UNIT
Maximum Instantaneous Forward Voltage Drop (Pulsed, T <sub>A</sub> = 25°C) @ I <sub>F</sub> = 10mA	SDR6638	V <sub>F1</sub>	0.8	Vdc
	SDR6642		0.8	
	SDR6643		1.0	
	SDR4150		0.74	
	SDR6638 @ I <sub>F</sub> = 200mA	V <sub>F2</sub>	1.1	Vdc
	SDR6642 @ I <sub>F</sub> = 100mA		1.2	
	SDR6643 @ I <sub>F</sub> = 100mA		1.2	
	SDR4150 @ I <sub>F</sub> = 100mA		0.92	
Maximum Instantaneous Forward Voltage Drop (Pulsed)	I <sub>F</sub> = 100mA, T <sub>A</sub> = -55°C	V <sub>F3</sub>	1.3	Vdc
Minimum Breakdown Voltage I <sub>r</sub> = 100 μA	SDR6638	B <sub>VR</sub>	125	Vdc
	SDR6642		100	
	SDR6643		75	
	SDR4150		75	
Maximum Reverse Leakage Current (300 μs Pulse Minimum , T <sub>A</sub> = 25°C)	SDR6638 @ V <sub>R</sub> = 20V	I <sub>R1</sub>	35	nA
	SDR6642 @ V <sub>R</sub> = 20V		25	
	SDR6643 @ V <sub>R</sub> = 20V		50	
	SDR4150 @ V <sub>R</sub> = 50V		100	
Maximum Reverse Leakage Current (300 μs Pulse Minimum , T <sub>A</sub> = 25°C)	SDR6638 @ V <sub>R</sub> = 100V	I <sub>R2</sub>	500	nA
	SDR6642 @ V <sub>R</sub> = 75V		500	
	SDR6643 @ V <sub>R</sub> = 50V		500	
Maximum Reverse Leakage Current (300 μs Pulse Minimum , T <sub>A</sub> = 150°C)	SDR6638 @ V <sub>R</sub> = 20V	I <sub>R3</sub>	50	μA
	SDR6642 @ V <sub>R</sub> = 20V		50	
	SDR6643 @ V <sub>R</sub> = 20V		75	
	SDR4150 @ V <sub>R</sub> = 50V		100	
Maximum Reverse Leakage Current (300 μs Pulse Minimum , T <sub>A</sub> = 150°C)	SDR6638 @ V <sub>R</sub> = 100V	I <sub>R4</sub>	100	μA
	SDR6642 @ V <sub>R</sub> = 75V		100	
	SDR6643 @ V <sub>R</sub> = 50V		160	
Maximum Junction Capacitance (T <sub>A</sub> = 25°C , f = 1MHz) V <sub>R</sub> = 0V	SDR6638	C <sub>J1</sub>	2.5	pf
	SDR6642		5.0	
	SDR6643		5.0	
	SDR4150		2.5	
Maximum Junction Capacitance (T <sub>A</sub> = 25°C , f = 1MHz) V <sub>R</sub> = 1.5V	SDR6638	C <sub>J2</sub>	2.0	pf
	SDR6642		2.8	
	SDR6643		2.8	
Maximum Reverse Recovery Time (I <sub>F</sub> = I <sub>R</sub> = 10 mA, I <sub>RR</sub> = 1 mA)	SDR6638	t <sub>rr</sub>	4.5	nsec
	SDR6642		5.0	
	SDR6643		6.0	
	SDR4150		4.0	

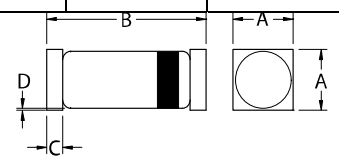
AXIAL		
DIMENSIONS		
DIM	MIN	MAX
A	.056"	.080"
B	.130"	.180"
C	1.00"	1.50"
D	.018"	.022"



SM		
DIMENSIONS		
DIM	MIN	MAX
A	.056"	.064"
B	.130"	.146"
C	.010"	.022"



SMS		
DIMENSIONS		
DIM	MIN	MAX
A	.070"	.085"
B	.180"	.210"
C	.022"	.028"
D	.001"	---



**NOTE:** All specifications are subject to change without notification.  
 SCD's for these devices should be reviewed by SSDI prior to release.

**DATA SHEET #: RC0126B**

**DOC**